Supporting Information for

Luminescence and slow magnetic relaxation of 2D

isostructural lanthanide metal-organic frameworks based

on nicotinate N-oxide and glutarate

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Table S1. Continuous Shape Measures calculation for the Dy(III) ion in 3.

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Dy1	EP-9	OPY-	НВРҮ-	JTC-9	JCCU-9	CCU-9	JCSAPR-9	CSAPR-9	JTCTPR-9	TCTPR-9	JTDIC-9	HH-9	MFF-9
		9	9										
ABOXIY	34.281	22.378	18.215	15.355	10.519	10.333	2.177	1.913	3.800	2.703	13.475	9.994	1.711

Dy1, nine-coordination

EP-9	1	D9h	Enneagon
OPY-9	2	C8v	Octagonal pyramid
HBPY-9	3	D7h	Heptagonal bipyramid
JTC-9	4	C3v	Johnson triangular cupola J3
JCCU-9	5	C4v	Capped cube J8
CCU-9	6	C4v	Spherical-relaxed capped cube
JCSAPR-9	7	C4v	Capped square antiprism J10
CSAPR-9	8	C4v	Spherical capped square antiprism
JTCTPR-9	9	D3h	Tricapped trigonal prism J51
TCTPR-9	10	D3h	Spherical tricapped trigonal prism
JTDIC-9	11	C3v	Tridiminished icosahedron J63
HH-9	12	C2v	Hula-hoop





Fig. S1. The simulative (black) and experimental (blue) powder X-ray diffraction patterns for 1.



Fig. S2. The simulative (black) and experimental (blue) powder X-ray diffraction patterns for 2.



Fig. S3. The simulative (black) and experimental (blue) powder X-ray diffraction patterns for 3.





Fig. S4. The coordination environments of the Eu atom in **1** (a), symmetry codes: a: 1/2-x, -1/2-y, 1-z; b: 1/2+x, 1/2+y, z; c: 1/2-x, 1/2-y, 1-z; d: -x, -y, 1-z; and 2D layer structure of **1** viewed down the *c*-axis (b).



Fig. S5. The coordination environments of the Gd atom in **2** (a), symmetry codes: a: 1/2-x, -1/2-y, 1-z; b: 1/2+x, 1/2+y, z; c: 1/2-x, 1/2-y, 1-z; d: -x, -y, 1-z; and 2D layer structure of **2** viewed down the *c*-axis (b).



Fig. S6. ${}^{5}D_{0}$ decay and fitted curves of complex 1 measured at room temperature. Emission was monitored at 615 nm and the excitation was performed at 400 nm.



Fig. S7. The absorption spectrum of the microcrystalline solids of compound 1 measured with an integrated sphere.



Fig. S8. $1/\chi$ versus *T* of **2**, the solid line represents the best theoretical fitting.



Fig. S9. *M* versus H/T plots at 2–6 K of **3**.



Fig. S10. *M* versus *H*/*T* plots at 2–6 K of **2**.



Fig. S11. AC susceptibilities measured in a 2.5 Oe ac magnetic field with a zero dc field for **3**.



Fig. S12. Plot of $\ln(\tau)$ versus $1/T_{\rm B}$ for 3, the solid lines represent the best fitting with the Arrhénius law.



Fig. S13. Frequency dependence of the in-phase (χ' , top) and out-of-phase (χ'' , bottom) ac susceptibility of **3** at 2 K. the solid lines represent the best fitting with the sum of two modified Debye functions



Fig. S14. Frequency dependence of the in-phase (χ' , top) and out-of-phase (χ'' , bottom) ac susceptibility of **3** at 3 K. the solid lines represent the best fitting with the sum of two modified Debye functions.



Fig. S15. Frequency dependence of the in-phase (χ' , top) and out-of-phase (χ'' , bottom) ac susceptibility of **3** at 4 K. the solid lines represent the best fitting with the sum of two modified Debye functions.



Fig. S16. Frequency dependence of the in-phase (χ' , top) and out-of-phase (χ'' , bottom) ac susceptibility of **3** at 5 K. the solid lines represent the best fitting with the sum of two modified Debye functions.



Fig. S17. Plot of *M* versus *H* at 1.9 K from –10000 to 10000 Oe for 3.

<i>T</i> (K)	$\chi_2(\text{cm}^3.\text{mol}^{-1})$	$\chi_1(\text{cm}^3.\text{mol}^{-1})$	$\chi_0(\text{cm}^3.\text{mol}^{-1})$	$\tau_1(s)$	α_1	$\tau_2(s)$	α_2
2	2.67585	3.34404	1.9481E-6	2.3645E-6	0.66397	0.43354	0.03787
3	2.73233	2.1514	0.18875	0.00001	0.68175	0.27605	0.00023
4	2.22941	1.9002	0.76017	0.00012	0.55338	0.21776	0.0284
5	2.06077	0.00061	2.49173	0.00009	0.71095	0.0061	0.1069

Table S2. Linear combination of two modified Debye model fitting parameters from 2 K to 5 K of **3** under 2k Oe dc field.